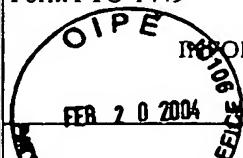


Form PTO-1449



INFORMATION DISCLOSURE CITATION
IN AN APPLICATION
(use several sheets if necessary)

Docket No.
P02,0480Serial No.
10/706,067

Romney R. Katti et al.

Filing Date
November 12, 2003

Group Art Unit

U.S. PATENT DOCUMENTS

Examiner's Initials		Document Number	Date	Name	Class	Subclass	Filing Date If appropriate
JM	AA	5,695,864	12/09/97	Slonczewski			
JM	AB	5,966,322	10/12/99	Pohm et al.			
JM	AC	5,949,707	09/07/99	Pohm et al.			
JM	AD	6,317,359 B1	11/13/01	Black et al.			
JM	AE	6,392,924 B1	05/21/02	Liu et al.			
	AF						
	AG						
	AH						
	AI						

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
	AJ							
	AK							
	AL							
	AM							
	AN							
	AO							
	AP							
	AQ							

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

JM	AR	James Daughton, "Magnetoresistive Random Access Memory (MRAM), 2/4/00, pgs. 1-13.
	AS	
	AT	
	AU	
	AV	
	AW	

Examiner /John McPherson/	Date Considered 05/10/2006
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.